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Megahertz non-contact luminescence decay time cryothermometry by means of ultrafast PbI_2 scintillator

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Realtime *in situ* temperature monitoring in difficult experimental conditions or inaccessible environments is critical for many applications. Non-contact luminescence decay time thermometry is often the method of choice for such applications due to a favorable combination of sensitivity, accuracy and robustness. In this work, we demonstrate the feasibility of an ultrafast PbI_2 scintillator for temperature determination, using the time structure of X-ray radiation, produced by a synchrotron. The decay kinetics of the scintillations was measured over the 8–107 K temperature range using monochromatic pulsed X-ray excitation. It is found that lead iodide exhibits a very fast and intense scintillation response due to excitons and donor-acceptor pairs, with the fast decay component varying between 0.08 and 0.5 ns – a feature that can be readily exploited for temperature monitoring. The observed temperature dependence of the decay time is discussed in terms of two possible mechanisms of thermal quenching – transition over activation barrier and phonon-assisted escape. It is concluded that the latter provides a better fit to the experimental results and is consistent with the model of luminescence processes in PbI_2 . We evaluated the sensitivity and estimated the accuracy of the temperature determination as ca. ± 6 K at 107 K, improving to ± 1.4 K at 8 K. The results of this study prove the feasibility of temperature monitoring, using ultrafast scintillation of PbI_2 excited by X-ray pulses from a synchrotron, thus enabling non-contact *in-situ* cryothermometry with megahertz sampling rate.

Temperature is a fundamental property of matter and plays an important role in many physical, chemical and biological processes. Solutions to challenging problems that modern science tends to face often necessitate experimenting in harsh and/or hardly accessible environments where accurate and reliable temperature monitoring is difficult. As an example, temperature is a very important parameter when aiming to protect biological samples from radiation damage during experiments that utilise powerful ionising radiation produced by modern synchrotron light sources^{1–4}. There is growing indication that intense irradiation applied to samples of microscopic size can significantly increase their temperature, which in turn causes sample degradation. This finding is likely to have even higher impact owing to the even higher brilliance that will result from planned upgrades of synchrotrons^{5,6}.

A novel method for non-contact monitoring of temperature in a vacuum environment has recently been developed and deployed for experimenting at the long-wavelength macromolecular crystallography (MX) beamline I23 at the Diamond Light Source (DLS)⁷. The temperature is derived from changes in the luminescence decay characteristics of a $\text{Bi}_4\text{Ge}_3\text{O}_{12}$ (BGO) scintillation sensor. Results from extensive testing have demonstrated the reliability and accuracy as well as the advantages of the technique⁸. In the temperature range of beamline operation (30–150 K) the error of temperature determination using a BGO scintillator is ± 1.6 K. The absence of electrical connections makes this system fully compatible with both the vacuum environment and the necessity of swift replacement and manipulation of samples.

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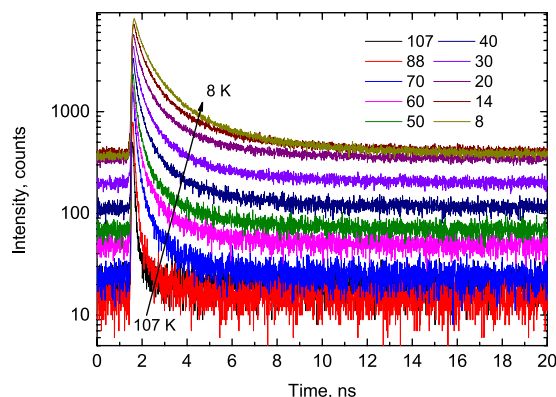


Figure 1. Decay curves of X-ray luminescence measured in the PbI_2 crystal at different temperatures from 8 to 107 K. The luminescence is excited by 60 ps pulses of synchrotron radiation ($E = 14 \text{ keV}$).

The method as it stands now has one intrinsic limitation, though. The luminescence decay time of the scintillation sensor used is within the 10^{-6} – 10^{-3} s range. This is a typical decay time for the majority of materials exhibiting thermally activated changes of luminescence properties at cryogenic temperatures. For measurements of the luminescence kinetics the technique employs a pulsed UV excitation source with a repetition rate of $< 1 \text{ kHz}$ ^{8,9}. However, throughout experimenting with X-rays, high-energy ionising radiation excites spurious luminescence in the material of the sensor, which exceeds the useful signal by a few orders of magnitude and prevents determination of the luminescence decay, thus making the measurements unreliable. This limitation significantly affects the merit of the technique and precludes application of this method for *in-situ* experiments that require X-rays. Thus, the most interesting and important information about temperature changes induced by ionised radiation remains elusive.

It has been realised that the time structure of the X-rays produced by synchrotrons offers an elegant way to circumvent this limitation. During normal operation of the DLS, electron bunches from the synchrotron ring emit a series of sharp X-ray pulses (FWHM of $\Delta t = 45 \text{ ps}$) at an interval of 2 ns. This gap can be used for measurements of very fast decay processes. Consequently, implementation of this idea requires a scintillator with ultrafast scintillation decay that also exhibits a significant change to that time constant in the temperature range of interest. The availability of a suitable scintillation material is key for this application. Motivated by this idea we initiated a search for a scintillator that satisfies these requirements.

Ultrafast temperature-dependent scintillations are observed in several semiconductors, e.g. CuI , HgI_2 , PbI_2 , ZnO , CdS , etc.¹⁰. Lead iodide has been investigated as a scintillator throughout the past century and there is a wealth of published data evidencing that it is very promising for application at cryogenic temperatures^{11–14}. Thus, we anticipated that due to a very high light yield of 40000 ph/MeV at 14 K and a prominent variation of the decay time constant over the temperature range of interest, 10–100 K¹⁴, PbI_2 can offer a viable solution for the application under consideration. In the work presented here we report on the results of a feasibility study and characterisation of a PbI_2 scintillation sensor for non-contact luminescence cryothermometry using pulsed X-ray excitation of a synchrotron light source.

Results

Lead iodide is crystallised in a rhombohedral crystal structure (space group $P\bar{3}m1$) with lattice constants $a = b = 4.56 \text{ \AA}$, $c = 6.98 \text{ \AA}$, $\alpha = \beta = 90^\circ$ and $\gamma = 120^\circ$. The crystal structure is formed by edge-sharing layers of PbI_6 octahedrons, running parallel to the ab -plane. The neighbouring layers are linked by Van der Waals forces, and that explains the high susceptibility of PbI_2 to cleaving. It is a narrow-band semiconductor with a direct band gap of 2.53 eV, density 6.16 g/cm^3 and melting point of 402°C .

There are several prior studies of luminescence and scintillation properties of PbI_2 stating that at cryogenic temperatures the emission arises from recombination of excitons and donor-acceptor pairs^{11,15–19}. When excited by X-rays, PbI_2 exhibits near-edge narrowband emission peaking at 520 nm with a very pronounced temperature dependence^{13,14}. Time-resolved studies carried out at 5 K showed that the radiative relaxation of excitons in PbI_2 exhibits a non-exponential decay with sub-nanosecond decay time constant. The latter is caused by the polariton effect i.e. a process controlled by excitons-phonon interaction²⁰. The decay time constant measured at excitation with X-rays are typically different from those observed at optical excitation. This difference is readily explained by the fact that X-rays produce ionisation tracks with a high density of charged particles, which transfer excitation energy to donor-acceptor pairs.

A key feature of the sensor for its use in non-contact thermometry is an ultrafast luminescence decay time constant. Therefore, we begin with presenting results on the X-ray-excited luminescence decay as a function of temperature. Figure 1 displays the change of the decay time response of PbI_2 emission to pulsed X-ray excitation as the temperature decreases from 107 to 8 K.

The decay curves exhibit very fast, non-exponential kinetics which is indicative of a complex emission process involving the radiative annihilation of free and bound excitons in semiconductors^{14,21–24}. Inspection of Fig. 1 proves that the decay curves of PbI_2 exhibit prominent change with temperature. Most obvious is the dramatic rise of the amplitude of the scintillation pulse. As the temperature decreases from 107 to 8 K there is an almost

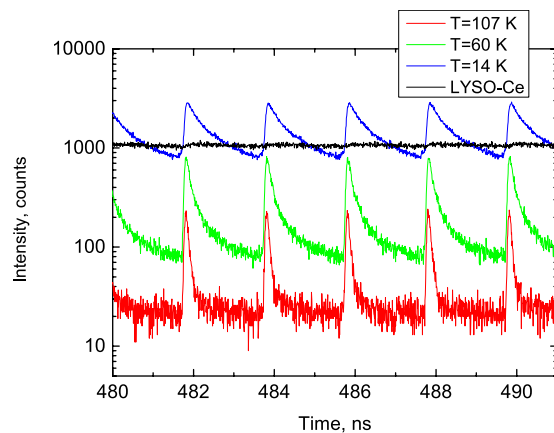


Figure 2. The sequence of X-ray pulses, emitted by the electron bunches of the synchrotron ring (time interval 2 ns, FWHM = 45 ps) as detected using a PbI₂ at T = 14 K (blue), 60 K (green), 107 K, (red) and LYSO-Ce scintillator (T = 292 K, black). The graphs demonstrate the exceptionally good timing resolution of the scintillation response for PbI₂ crystal as opposed to the completely saturated and featureless signal from LYSO-Ce.

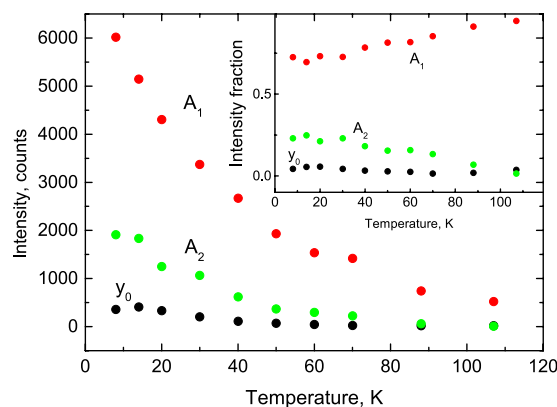


Figure 3. Temperature dependence of amplitudes obtained from the fitting of the decay curves of PbI₂ with a sum of two exponential functions: $y = A_1 \exp(-t/\tau_1) + A_2 \exp(-t/\tau_2) + y_0$. The inset shows fractional contributions of the components to the total emission amplitude.

ten-fold increase of the peak intensity, which is consistent with previous observations^{13,14}. Careful inspection of the data reveals that the shape of the scintillation pulse in PbI₂ also undergoes noticeable changes with cooling, indicating a slowing down in the recombination dynamics. This is due to the reduction of the luminescence decay rate with a decrease of temperature, commonly observed in many scintillation materials. Another feature of PbI₂, which is crucial for the envisaged application, is the ultrafast decay time that allows measurements of decay curves over a narrow time interval between consecutive X-ray pulses. Figure 2 displays the sequence of X-ray pulses from the synchrotron (FWHM = 45 ps, interval $\Delta t = 2$ ns) detected by PbI₂ at different temperatures. This is a very clear demonstration of the possibility for such measurements with a megahertz sampling rate.

Given that non-contact thermometry relies totally on the changes of the decay curves with temperature, all these features are very important from the viewpoint of the present study. Therefore, for a more quantitative evaluation of these properties and trends, we fitted the measured decay curves with a sum of exponential functions: $f(t) = \sum_i A_i \exp(-t/\tau_i) + y_0$, where A_i is the amplitude, τ_i the decay time constant and y_0 the background. It should be noted that the multi-exponential fit is widely applied to characterise the processes of radiative decay of excitons and donor-acceptor pairs in semiconductors^{13,21–25}. The quality of the fit was only marginally different between two- and three exponential fits. Two exponentials and a constant background is sufficient for an adequate representation of the measured decay curves. The fitting parameters for PbI₂ as functions of temperature are shown in Figs 3 and 4.

Analysis of these plots reveals further details of the temperature evolution of the luminescence kinetics of the crystal. The total amplitude of the fast (A_1), and slow (A_2) emission components, as well as the background (y_0) exhibit a pronounced increase with cooling (see Fig. 3). Interestingly, for the fractional contributions of the two emission components, the opposite trends are observed (see inset to Fig. 3). With cooling, the fractional contribution of the slow component in the decay curve becomes more pronounced, rising from 0 to 25%, while the background increases from 0 to 5%, and the fractional contributions of the fast component gradually reduce

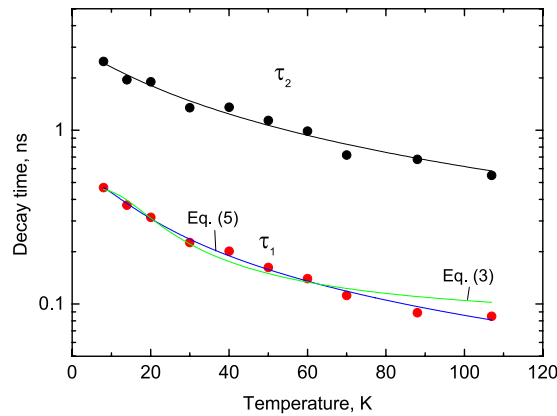


Figure 4. Temperature dependence of decay time constants of PbI_2 . The lines show the best fit of the temperature dependence to different models a) the model of thermal activation over an energy barrier (Equation (3), green line) and b) multi-phonon scattering (Equation (5) blue line). The best fit for $\tau_1 = f(T)$ was obtained using Equation (5) with the following parameters: $\tau_i = 3 \times 10^6 \text{ s}$, $\Gamma_0 = 1.90 \pm 0.08 \times 10^9 \text{ s}^{-1}$, $E_{ph} = 1.54 \text{ meV}$, $n = 1$.

from 100 to 70%. Figure 4 shows the temperature dependence of the fast (τ_1) and slow (τ_2) decay constants. As expected, both decay constants increase with the crystal cooling over the entire measured range (8–107 K). It is this characteristic of PbI_2 emission that is of primary importance for the non-contact temperature monitoring.

Discussion

The data in Fig. 4 demonstrate a relatively large dependence of the decay time constant on temperature due to considerable thermal quenching. The origin of the observed dependence of the decay time versus temperature can be understood by considering the dynamics of radiative and non-radiative transitions between the excited and ground states of the emission center. In the framework of this consideration, the measured transition rate (inverse of luminescence decay constant τ) can be determined as sum of radiative (k_r) and non-radiative (k_{nr}) rates:

$$\frac{1}{\tau} = k_r + k_{nr} = \frac{1}{\tau_r} + \frac{1}{\tau_{nr}} \quad (1)$$

In insulators where luminescence originates from radiative decay of emission centers (impurity or defect) the changes of decay time with temperature are traditionally attributed to the process of depopulation of excited levels of the emission center due to thermally induced transition of excited particles over the energy barrier that leads to the non-radiative decay. The rate associated with the non-radiative process exhibits a strong temperature dependence, thus controlling the variation of the non-radiative decay with temperature:

$$\frac{1}{\tau_{nr}} = K \exp\left(\frac{-\Delta E}{kT}\right) \quad (2)$$

where K is the probability of non-radiative decay, ΔE is the activation energy for the non-radiative transitions, and k is Boltzmann's constant. Substituting (2) into (1) brings about the classical formula which allows to describe many practical cases of the $\tau = f(T)$ dependence:⁹

$$\frac{1}{\tau} = \frac{1}{\tau_r} + K \exp\left(\frac{-\Delta E}{kT}\right) \quad (3)$$

A complementary mechanism of thermal de-activation due to multi-phonon scattering is often considered in semiconductors, where the luminescence originates from recombination of free carriers with donors and/or acceptors^{26–28}. From the viewpoint of the related model, the non-radiative recombination occurs because of phonon-assisted escape of carriers out of the emission centre. This is possible because multiple types of donor and acceptor centers create in the bandgap of semiconductor a multitude of intermediate levels that can be involved in phonon-assisted processes. There, the temperature dependent change of the non-radiative decay rate is defined as thermally aided scattering of carriers via phonon emission. The theoretical expression for the non-radiative decay is given by the following expression:²⁹

$$\frac{1}{\tau_{nr}} = \Gamma_0 \left[\frac{1}{\exp\left(\frac{E_{ph}}{kT}\right) - 1} + 1 \right]^n, \quad (4)$$

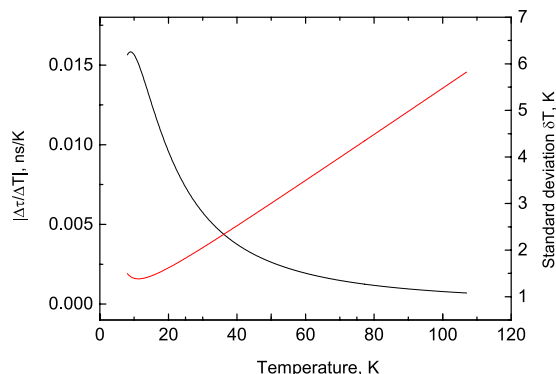


Figure 5. The temperature variation of the sensitivity $|(\Delta\tau/\Delta T)|$ (black) and uncertainty of temperature measurements (red) using a PbI_2 scintillation sensor. The curves are calculated using the fitted $\tau_1 = f(T)$ dependence, displayed in Fig. 4.

where Γ_0 is the probability of non-radiative decay at $T=0$, E_{ph} is the phonon energy and n is the number of phonons involved in the process. After rearranging (4) and substituting into (1) the expression for the temperature dependence of the luminescence decay constant it becomes

$$\frac{1}{\tau} = \frac{1}{\tau_r} + \Gamma_0 \left(1 - \exp\left(\frac{-E_{ph}}{kT}\right) \right)^{-n}. \quad (5)$$

We tested both models to fit our experimental data (see Fig. 4) and found that Equation (5) gives a superior result: the goodness of fit defined as chi square is 0.978 for the first model and 0.992 for the multi-phonon scattering model. This finding provides convincing evidence that phonon-assisted processes control thermally induced effects occurring in PbI_2 at low temperatures.

Having established the analytical expression for the $\tau = f(T)$ dependence in PbI_2 we can now evaluate the potential of the material for non-contact measurements of temperature under the experimental conditions that provided the results under discussion. The most important characteristics of performance of a temperature sensor are sensitivity and accuracy. The sensitivity is determined as a derivative $\Delta\tau/\Delta T$ that determines the slope of the $\tau = f(T)$ curve. It is desirable to have a sufficiently large value of this parameter over the entire temperature range of interest or in other words a sharp fall-off of the decay time with temperature. From the data in Fig. 4 it is fairly obvious that the fast decay constant exhibits the steeper slope. Moreover, the error of fitting the fast decay constant is almost a factor two smaller over the entire temperature range of interest in comparison with the slow decay constant. This is because the amplitude of the fast component is much higher, resulting in a higher signal-to-noise ratio. Therefore, the fast decay constant is invariably preferred for temperature monitoring.

Using the results of the fit to the multi-phonon model, we calculated the variation of $\Delta\tau/\Delta T$ with temperature. According to the plot displayed in Fig. 5, the sensitivity increases from 6×10^{-4} to 1.5×10^{-2} ns/K as temperature decreases from 107 to 8 K. It is pertinent to remark that the sensitivity also has a direct impact on the precision of temperature measurements. To estimate the accuracy of the temperature determination using PbI_2 we analyzed multiple traces of decay curves similar to the one displayed in Fig. 2 and estimated that the error in the measurement of the fast decay time constant is $\varepsilon = \pm 6\%$. This allows the calculation of the uncertainty of determining the temperature δT from the $\tau = f(T)$ dependence and sensitivity curve $\Delta\tau/\Delta T = f(T)$ using the following formula³⁰:

$$\delta T = \varepsilon \tau(T) \left(\frac{\Delta\tau}{\Delta T} \right)^{-1}. \quad (6)$$

Figure 5 shows that the measurement errors change significantly over the examined temperature range. The uncertainty of the temperature determination is ± 1.4 K at 8 K but gradually increases to ± 6 K at 107 K. The enhanced magnitude of the error towards higher temperatures is expected; it is due to the reduced sensitivity of PbI_2 in this range. At this stage the obtained accuracy in temperature reading is worse than what is typically achieved by non-contact luminescence decay techniques that utilise conventional near room temperature sensors (± 1 K or better)^{31–34}. However, it is comparable with the accuracy demonstrated by the method when used for the measurements of cryogenic temperatures^{35,36}. It is also expected that the accuracy can be significantly improved through the optimisation of hardware, detection method and data analysis. Therefore, we are confident that the PbI_2 scintillator with subnanosecond time resolution can open a new domain for application in temperature measurements, enabling fast non-contact luminescence decay time thermometry.

Conclusion

In this work we investigated the temperature-induced changes in the kinetics of ultrafast scintillations in PbI_2 excited by pulsed monochromatic 14 keV X-rays from a synchrotron source. When cooled to below 100 K this material exhibits intense emission with very fast decay at X-ray excitation. We monitored changes of the luminescence kinetics with cooling from 107 to 8 K and determined the temperature dependence of the decay

characteristics by fitting the measured decay curves by a sum of two exponential functions. It has been found that between 107 and 8 K, lead iodide exhibits a very prompt and intense scintillation response, with the fast decay component varying between 0.08 and 0.5 ns, making this scintillator suitable for temperature monitoring.

To explain the observed temperature change of the decay time we examined two theoretical models. By fitting the measured $\tau = f(T)$ dependence to the pertinent analytical equations given by the models, we demonstrated that in PbI_2 temperature changes of the luminescence decay time are governed by the non-radiative recombination process due to phonon-assisted escape of carriers out of the emission centre.

Motivated by the idea of non-contact decay time thermometry we evaluated the sensitivity of the PbI_2 sensor and estimated the accuracy. It is found that the error of temperature determination is ca. ± 6 K at 107 K reducing to ± 1.4 K at 8 K. Overall this clearly demonstrates the potential of the PbI_2 scintillator for temperature monitoring by measuring the luminescence decay curve excited by X-ray pulses. Crucially, the ultrafast emission decay time of PbI_2 allows measurements to be done using the standard bunch structure of X-ray emission produced by DLS and other synchrotrons. This proves the feasibility of the fast non-contact luminescence decay time cryothermometry with megahertz sampling rate and we aim to develop this technique further.

Materials and Methods

The sample of PbI_2 with approximate dimensions $4 \times 5 \times 1.5$ mm³ was cleaved from an ingot that has been grown by using the Bridgman technique in a quartz ampule. The scintillation decay curves of the crystals were measured at the beamline B16 of DLS, using a 14 keV monochromatic X-ray beam from the synchrotron. The measurements were carried out at a special beam condition suitable for time-resolved experiments³⁷ by triggering on a single X-ray pulse with FWHM of $\Delta t = 60$ ps, separated from the following pulse by a 250 ns gap. The sample was glued with silver adhesive to the holder of a continuous-flow, He-cryostat (Oxford Instruments). A controller stabilized the temperature in the cryostat using a PID feedback loop with a Si-diode as a temperature sensor and a resistive heater. The cryostat was attached to an XYZ-translation stage to facilitate swift alignment. The cryostat has an 0.2 mm thick aluminised Mylar window, transparent for 14 keV X-rays. Through this window the X-ray beam 1×1 mm² with a flux of $\sim 10^9$ ph/(s·mm²) was irradiating the sample placed at 45° to the incoming radiation while the luminescence was collected in reflection mode at 45° through a quartz window. The emission was detected using an ID100 single photon counting detector sensitive over a 400–900 nm spectral range and a PicoHarp 300 time-correlated single photon counting module.

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Author Contributions

V.B.M. and H.K. conceived idea, R.G. produced the crystal, V.B.M. and L.B. designed the experiment, V.B.M., H.K. and K.K. carried out measurements and analysed the data, V.B.M. and H.K. drafted the manuscript. All authors contributed to the manuscript revision.

Additional Information

Competing Interests: The authors declare no competing interests.

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